

# **DS1007** 7-1 Silicon Delay Line

IN4

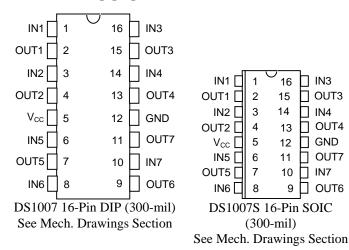
OUT7

#### www.dalsemi.com

### **FEATURES**

- All-silicon time delay
- 7 independent buffered delays
- Delay tolerance  $\pm 2$  ns
- Four delays can be custom set between 3 ns and 10 ns
- Three delays can be custom set between 9 ns and 40 ns
- Delays are stable and precise
- **Economical**
- Auto-insertable, low profile
- Surface mount 16-pin SOIC
- Low-power CMOS
- TTL/CMOS-compatible
- Vapor phase, IR and wave solderable
- Custom specifications available
- Quick turn prototypes

## PIN ASSIGNMENT



#### PIN DESCRIPTION

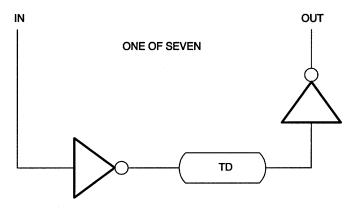
IN1 - IN7 - Inputs Out1 - Out7- Outputs **GND** - Ground  $V_{CC}$ - +5 Volts

#### DESCRIPTION

The DS1007 7-in-1 Silicon Delay Line provides seven independent delay times which are set by Dallas Semiconductor to the customer's specification. The delay times can be set from 3 ns to 40 ns with an accuracy of ±2 ns at room temperature. The device is offered in both a 16-pin DIP and a 16-pin SOIC. Since the DS1007 is an all-silicon solution, better economy and reliability are achieved when compared to older methods using hybrid technology. The DS1007 reproduces the input logic state at the output after the fixed delay. Dallas Semiconductor can customize standard products to meet special needs. For special requests and rapid delivery, call (972) 371–4348.

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## **LOGIC DIAGRAM** Figure 1



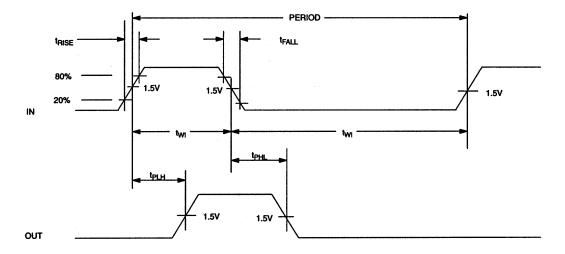
PULSE WIDTH > 100% OF DELAY

## PART NUMBER DELAY TABLE (t<sub>PLH</sub>) Table 1

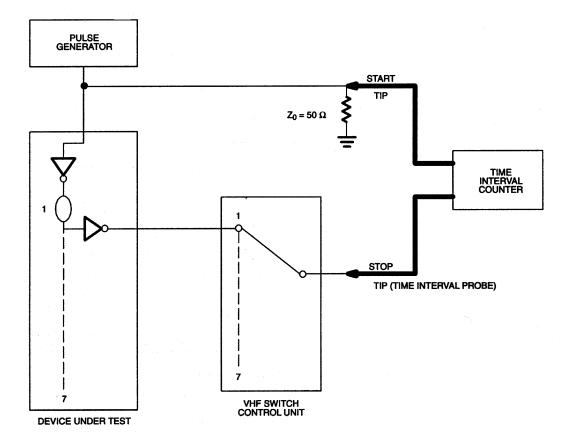
	(PLH) 14010 1						
PART#	OUT1	OUT2	OUT3	OUT4	OUT5	OUT6	OUT7
DS1007-1	3ns	4ns	5ns	6ns	9ns	13ns	18ns
DS1007-2	4	6	8	10	12	14	16
DS1007-3	3	3	3	3	10	10	10
DS1007-4	4	4	4	4	12	12	12
DS1007-5	5	5	5	5	15	15	15
DS1007-6	6	6	6	6	20	20	20
DS1007-7	7	7	7	7	25	25	25
DS1007-8	8	8	8	8	30	30	30
DS1007-9	9	9	9	9	35	35	35
DS1007-10	10	10	10	10	40	40	40
DS1007-11	3	4	6	8	10	12	14
DS1007-12	3	4	6	8	10	15	20
DS1007-13	3	4	6	8	12	15	20
DS1007-14	7	7	7	7	9	9	9

Custom delays available. Out 1 through Out 4 can be custom set from 3 to 10 ns (leading edge only accuracy). Out 5 through Out 7 can be set from 9 to 40 ns (both leading and trailing edge accuracy).

# TIMING DIAGRAM: SILICON DELAY LINE Figure 2



## **TEST CIRCUIT** Figure 3



## **ABSOLUTE MAXIMUM RATINGS\***

Voltage on Any Pin Relative to Ground -1.0 V to +7.0 VOperating Temperature  $0^{\circ}\text{C to } 70^{\circ}\text{C}$ Storage Temperature  $-55^{\circ}\text{C to } +125^{\circ}\text{C}$ Soldering Temperature  $260^{\circ}\text{C for } 10 \text{ seconds}$ Short Circuit Output Current 50 mA for 1 second

## DC ELECTRICAL CHARACTERISTICS

 $(0^{\circ}\text{C to } 70^{\circ}\text{C}; \text{V}_{\text{CC}} = 5.0\text{V} \pm 5\%)$ 

PARAMETER	SYM	TEST	MIN	TYP	MAX	UNITS	NOTES
		CONDITION					
Supply Voltage	$V_{CC}$		4.75	5.00	5.25	V	1
High Level Input	$V_{IH}$		2.2		$V_{CC} + 0.5$	V	1
Voltage							
Low Level Input	$V_{IL}$		-0.5		0.8	V	1
Voltage							
Input Leakage	$I_{I}$	$0.0V \le V_I \le V_{CC}$	-1.0		1.0	uA	
Current							
Active Current	$I_{CC}$	V <sub>CC</sub> =Max;		40.0	70.0	mA	2
		Period=Min.					
High Level Output	$I_{OH}$	V <sub>CC</sub> =Min.			-1.0	mA	
Current		$V_{OH}=2.4V$					
Low Level Output	$I_{OL}$	V <sub>CC</sub> =Min.	12.0			mA	
Current		$V_{OL}=0.5V$					

### **AC ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C; V_{CC} = 5V \pm 5\%)$ 

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PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Pulse Width	$t_{ m WI}$	$100\%$ of $t_{PLH}$			ns	
Input to Output	$t_{PLH}$		Table 1		ns	3, 4, 5
(leading edge)						
Power-up Time	$t_{\mathrm{PU}}$			100	ms	7
	Period	3 (t <sub>WI</sub> )			ns	6

CAPACITANCE

 $(T_A = 25^{\circ}C)$ 

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Capacitance	$C_{IN}$		5	10	pF	

<sup>\*</sup> This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

#### NOTES:

- 1. All voltages are referenced to ground.
- 2. Measured with outputs open.
- 3.  $V_{CC} = 5V @25^{\circ}C$ . Delays accurate on rising edges within  $\pm 2$  ns.
- 4. See Test Conditions below.
- 5. All output delays in the same speed output tend to vary unidirectionally with temperature or voltage range (i.e., if Out 2 slows down, all other outputs also slow down).
- 6. Period specifications may be exceeded; however, accuracy will be application-sensitive (decoupling, layout, etc.).
- 7.  $t_{PU} = 0$  ms for Out 1 through Out 4.

#### **TERMINOLOGY**

**Period:** The time elapsed between the leading edge of the first pulse and the leading edge of the following pulse.

 $t_{WI}$  (**Pulse Width**): The elapsed time on the pulse between the 1.5V point on the leading edge and the 1.5V point on the trailing edge, or the 1.5V point on the trailing edge and the 1.5V point on the leading edge.

 $t_{RISE}$  (Input Rise Time): The elapsed time between the 20% and the 80% point on the leading edge of the input pulse.

 $\mathbf{t_{FALL}}$  (Input Fall Time): The elapsed time between the 80% and the 20% point on the trailing edge of the input pulse.

 $\mathbf{t}_{PLH}$  (**Time Delay, Rising**): The elapsed time between the 1.5V point on the leading edge of the input pulse and the 1.5V point on the leading edge of the corresponding output pulse.

## **TEST SETUP DESCRIPTION**

Figure 3 illustrates the hardware configuration used for measuring the timing parameters on the DS1007. The input waveform is produced by a precision pulse generator under software control. Time delays are measured by a time interval counter (20 ps resolution) connected between the input and each output. Each output is selected and connected to the counter by a VHF switch control unit. All measurements are fully automated, with each instrument controlled by a central computer over an IEEE 488 bus.

## **TEST CONDITIONS**

## **INPUT:**

Ambient Temperature:  $25^{\circ}\text{C} \pm 3^{\circ}\text{C}$ Supply Voltage (V<sub>CC</sub>):  $5.0\text{V} \pm 0.1\text{V}$ 

Input Pulse: High =  $3.0V \pm 0.1V$ 

 $Low = 0.0V \pm 0.1V$ 

Source Impedance: 50 ohm max.
Rise and Fall Time: 3.0 ns max.
Pulse Width: 500 ns
Period: 1 µs

### **OUTPUT:**

Each output is loaded with the equivalent of one 74F04 input gate. Delay is measured at the 1.5V level on the rising edge.

#### NOTE:

Above conditions are for test only and do not restrict the operation of the device under other data sheet conditions.